

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Available in uni-directional and bi-directional
- 600 W peak pulse power capability with a 10/1000 μ s waveform, repetitive rate (duty cycle): 0.01 %
- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 or P/NHM3

MECHANICAL DATA

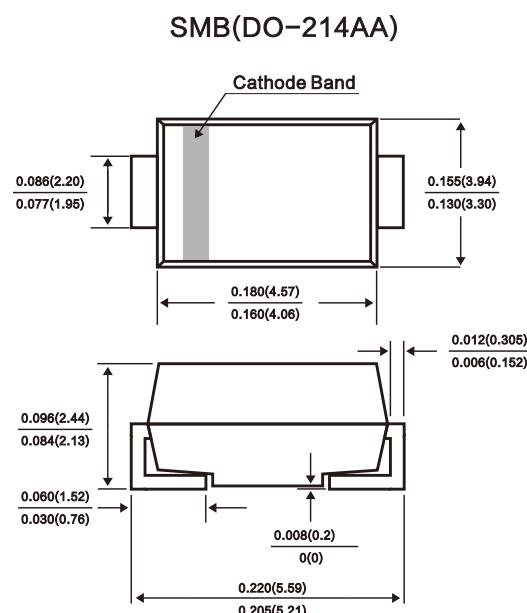
Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating
 Base P/N-E3 - RoHS-compliant, commercial grade
 Base P/N-M3 - halogen-free, RoHS-compliant, commercial grade
 Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified
 Base P/NHM3_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified
 ("_X" denotes revision code e.g. A, B, and only available for 250 V to 540 V type)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3, M3, HE3, and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: for uni-directional types the band denotes cathode end, no marking on bi-directional types



Dimensions in inches and (millimeters)

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT
Peak power dissipation with a 10/1000 μ s waveform ⁽¹⁾⁽²⁾ (fig. 1)	P_{PPM}	600	W
Maximum Instantaneous Forward Voltage at 50.0A for Unidirectional Only (Note 4)	V_F	3.5	Volts
Power dissipation on infinite heatsink at $T_A = 50^\circ\text{C}$	P_D	5.0	W
Peak forward surge current 8.3 ms single half sine-wave uni-directional only ⁽²⁾	I_{FSM}	100	A
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +150	°C

Notes

(1) Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25^\circ\text{C}$ per fig. 2

(2) Mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pads to each terminal

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)**Notes**

- (1) Pulse test: $t_p \leq 50$ ms
- (2) Surge current waveform per fig. 3 and derate per fig. 2
- (3) For bi-directional types with V_{WM} of 10 V and less, the I_D limit is doubled
- (4) All terms and symbols are consistent with ANSI/IEEE CA62.35
- (5) $V_F = 3.5$ V at $I_F = 50$ A (uni-directional only)

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)

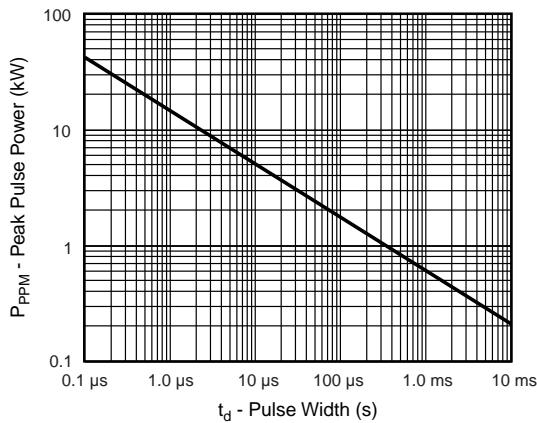


Fig. 1 - Peak Pulse Power Rating Curve

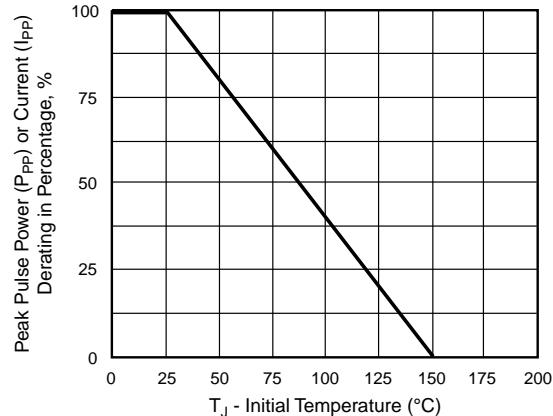


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

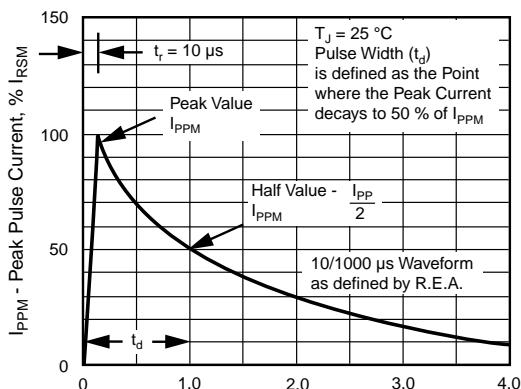


Fig. 3 - Pulse Waveform

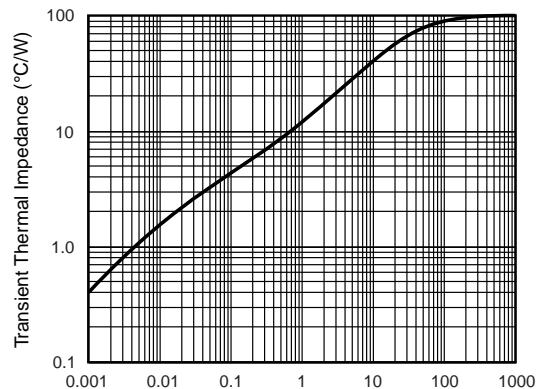


Fig. 5 - Typical Transient Thermal Impedance

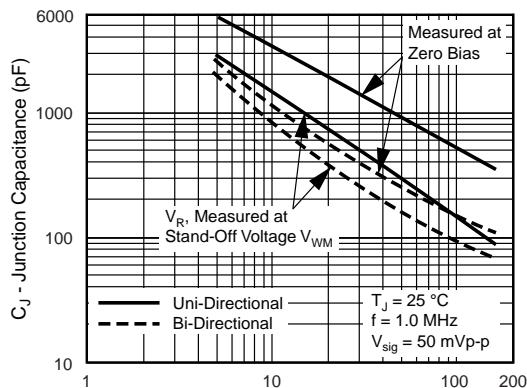


Fig. 4 - Typical Junction Capacitance

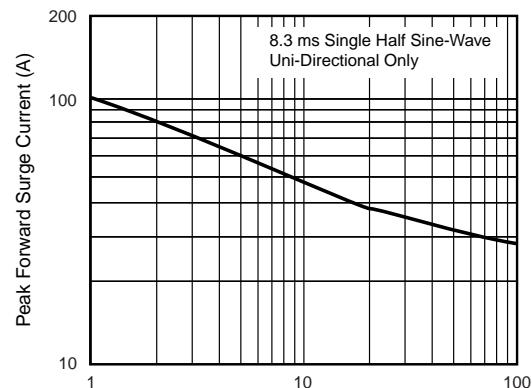


Fig. 6 - Maximum Non-Repetitive Peak Forward Surge Current

ORDERING INFORMATION

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for ESD Suppressors / TVS Diodes category:

Click to view products by Youtai manufacturer:

Other Similar products are found below :

[60KS200C](#) [D18V0L1B2LP-7B](#) [D5V0F4U5P5-7](#) [DESD5V0U1BB-7](#) [NTE4902](#) [P4KE27CA](#) [P6KE11CA](#) [P6KE39CA-TP](#) [P6KE8.2A](#)
[SA110CA](#) [SA60CA](#) [SA64CA](#) [SMBJ12CATR](#) [SMBJ33CATR](#) [SMBJ8.0A](#) [ESD101-B1-02ELS](#) [E6327](#) [ESD105-B1-02EL](#) [E6327](#) [ESD112-B1-02EL](#) [E6327](#) [ESD119B1W01005E6327XTSA1](#) [ESD5V0L1B02VH6327XTSA1](#) [ESD7451N2T5G](#) [19180-510](#) [CPDT-5V0USP-HF](#)
[3.0SMCJ33CA-F](#) [3.0SMCJ36A-F](#) [HSPC16701B02TP](#) [D3V3Q1B2DLP3-7](#) [D55V0M1B2WS-7](#) [DESD5V0U1BL-7B](#) [DRTR5V0U4SL-7](#)
[SCM1293A-04SO](#) [ESD200-B1-CSP0201](#) [E6327](#) [SM12-7](#) [SMLJ45CA-TP](#) [CEN955 W/DATA](#) [82350120560](#) [VESD12A1A-HD1-GS08](#)
[CPDUR5V0R-HF](#) [CPDQC5V0U-HF](#) [CPDQC5V0USP-HF](#) [CPDQC5V0-HF](#) [D1213A-01LP4-7B](#) [D1213A-02WL-7](#) [MMAD1108/TR13](#)
[5KP100A](#) [5KP15A](#) [5KP18A](#) [5KP48A](#) [5KP90A](#) [5KP90CA](#)